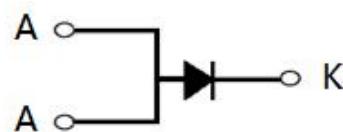
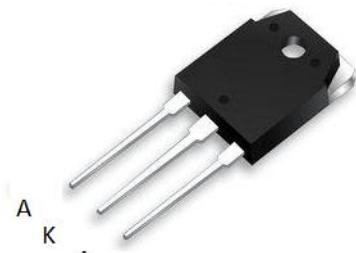


High Power Products

**FRED**  
**Ultrafast Soft Recovery Diode, 80A****Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low  $I_R$  value
- High surge capacity
- Epitaxial chip construction

**Product Summary**

$V_R$	400 V
$I_F(AV)$	80A
$t_{rr}$	32ns

**Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

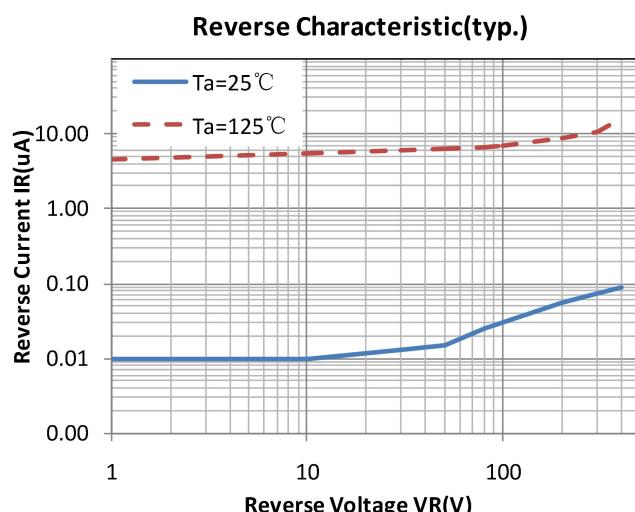
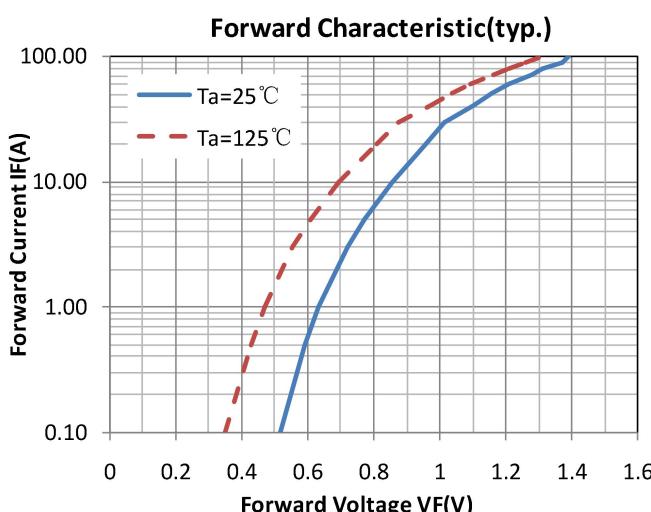
<b>Absolute Maximum Ratings</b>				
<b>Parameter</b>	<b>Symbol</b>	<b>Test Conditions</b>	<b>Values</b>	<b>Units</b>
Repetitive peak reverse voltage	$V_{RRM}$		400	V
Continuous forward current	$I_F(AV)$	$T_c = 110^\circ C$	80	A
Single pulse forward current	$I_{FSM}$	$T_c = 25^\circ C$	750	
Maximum repetitive forward current	$I_{FRM}$	Square wave, 20kHZ	160	$^\circ C$
Operating junction	$T_j$		175	
Storage temperatures	$T_{stg}$		-55 to +175	$^\circ C$

**Electrical characteristics (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> =100μA	400			V
Forward voltage (Per Diode)	V <sub>F</sub>	I <sub>F</sub> =80A		1.30	1.60	
		I <sub>F</sub> =80A, T <sub>j</sub> =125°C		1.20	1.50	
Reverse leakage current(Per Diode)	I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub>			50	μA
		T <sub>j</sub> =150°C, V <sub>R</sub> =400V			500	
Reverse recovery time(Per Diode)	t <sub>rr</sub>	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		43	55	ns
		I <sub>F</sub> =1A, V <sub>R</sub> =30V, di/dt =200A/us		32	40	

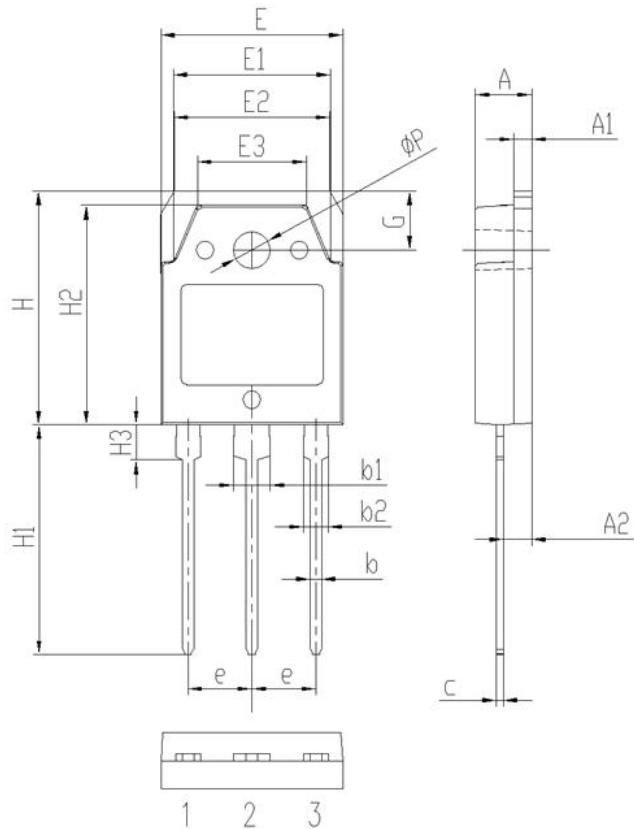
**Thermal characteristics**

Paramter	Symbol	Typ	Units
Junction-to-Case	R <sub>θJC</sub>	0.8	°C/W

**Electrical performance (typic)**


## Package Information

### TO-3PB PACKAGE



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.60	5.00
A1	1.30	1.70
A2	2.20	2.60
b	0.80	1.20
b1	2.90	3.30
b2	1.90	2.30
c	0.40	0.80
e	5.25	5.65
E	15.3	15.7
E1	13.2	13.6
E2	13.1	13.5
E3	9.10	9.50
H	19.7	20.1
H1	19.1	20.1
H2	18.3	18.7
H3	2.80	3.20
G	4.80	5.20
ΦP	3.00	3.40